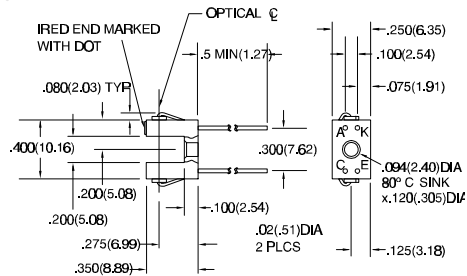


- Choice of phototransistor or photodarlington output
- Low profile package
- Wide operating temperature range (- 55°C to +100°C)
- 0.200 in.(5.08 mm) slot width



The HOA1875 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1875- 001, - 002) or photodarlington (HOA1875- 003) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1875 series has a 0.050 in.(1.27 mm) dia. detector aperture and employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Tolerance	3 plc decimals	$\pm 0.010(0.25)$
	2 plc decimals	$\pm 0.020(0.51)$



DIM_047.cdr

HOA1875

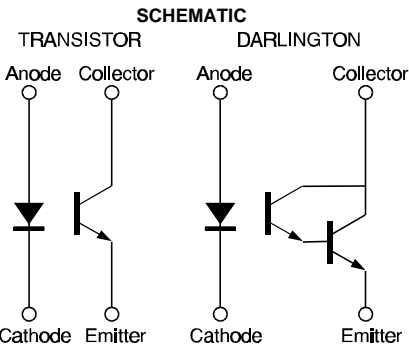
Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage HOA1875-001, -002 HOA1875-003	$V_{(BR)CEO}$	30 15			V	$I_C=100\text{ }\mu\text{A}$
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current HOA1875-001, -002 HOA1875-003	I_{CE0}			100 250	nA	$V_{CE}=10\text{ V}$ $I_F=0$
COUPLED CHARACTERISTICS						
On-State Collector Current HOA1875-001 HOA1875-002 HOA1875-003	$I_{C(ON)}$	0.15 0.6 1.8			mA	$V_{CE}=5\text{ V}$ $I_F=30\text{ mA}$
Collector-Emitter Saturation Voltage HOA1875-001 HOA1875-002 HOA1875-003	$V_{CE(SAT)}$			0.4 0.4 1.1	V	$I_F=20\text{ mA}$ $I_C=20\text{ }\mu\text{A}$ $I_C=80\text{ }\mu\text{A}$ $I_C=230\text{ }\mu\text{A}$
Rise And Fall Time HOA1875-001, -002 HOA1875-003	t_r, t_f		15 75		μs	$V_{CC}=5\text{ V}$, $I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$ $R_L=100\text{ }\Omega$

ABSOLUTE MAXIMUM RATINGS
(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C
Storage Temperature Range -55°C to 125°C
Soldering Temperature (10 sec) 260°C

IR EMITTER		
Power Dissipation	75 mW ⁽¹⁾	
Reverse Voltage	3 V	
Continuous Forward Current	50 mA	
DETECTOR		
	TRANS.	DARLINGTON
Collector-Emitter Voltage	30 V	15 V
Emitter-Collector Voltage	5 V	5 V
Power Dissipation	75 mW ⁽¹⁾	75 mW ⁽¹⁾
Collector DC Current	30 mA	30 mA



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

HOA1875

Transmissive Sensor

Fig. 1 IRED Forward Bias Characteristics

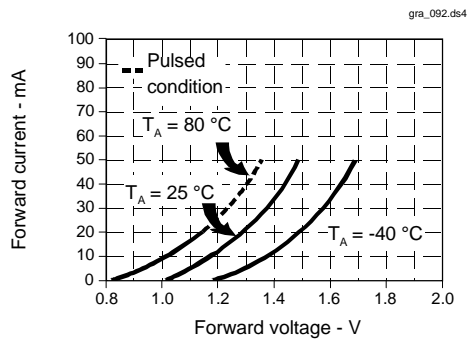


Fig. 2 Non-Saturated Switching Time vs Load Resistance

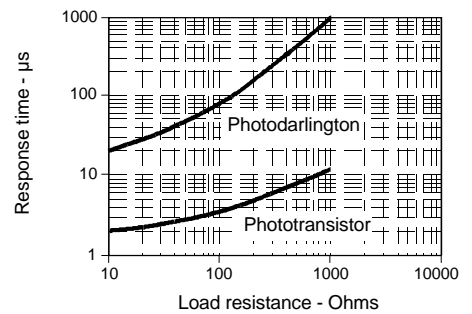


Fig. 3 Dark Current vs Temperature

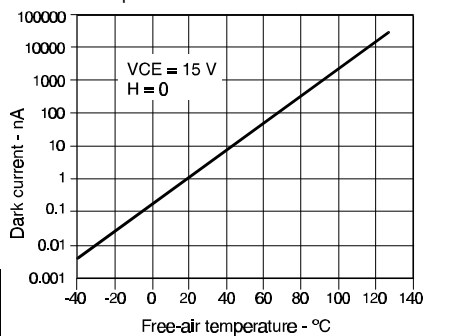
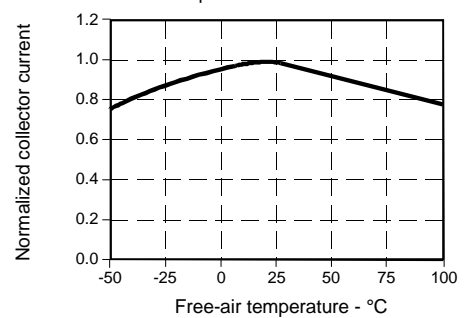


Fig. 4 Collector Current vs Ambient Temperature



All Performance Curves Show Typical Values



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